

EVALUATION KIT
AVAILABLE

Step-Up Converter for Handheld Applications

MAX8969

General Description

The MAX8969 is a simple 1A step-up converter in a small package that can be used in any single-cell Li-ion application. This IC provides protection features such as input undervoltage lockout, short circuit, and overtemperature shutdown.

The IC transitions to skip mode seamlessly under light-load conditions to improve efficiency. Under these conditions, switching occurs only as needed, reducing switching frequency and supply current to maintain high efficiency.

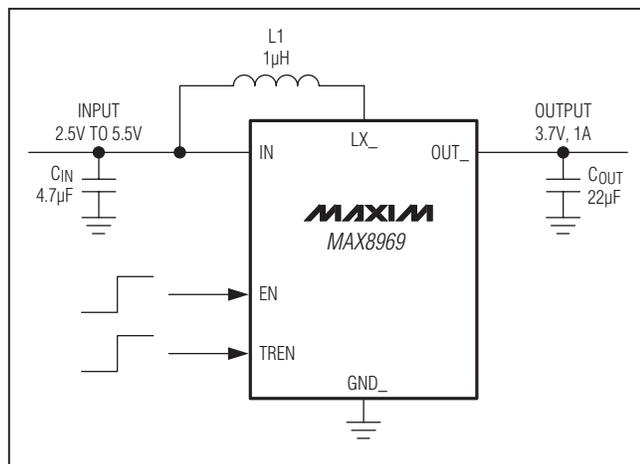
When the input voltage is sufficient to drive the load, the IC can be operated in track mode or automatic track mode (ATM). In track mode, the p-channel MOSFET acts as a current-limited load switch and quiescent current is as low as 30 μ A under a no-load condition. In ATM mode, the p-channel MOSFET acts as a current-limited load switch and quiescent current is as low as 60 μ A under a no-load condition. In ATM mode, the internal boost circuitry is enabled, allowing for fast transitions into boost mode.

The IC is available in a small, 1.25mm x 1.25mm, 9-bump WLP (0.4mm pitch) package.

Applications

Cell Phones
Smartphones
Mobile Internet Devices
GPS, PND
eBooks

Typical Operating Circuit



True Shutdown is a trademark of Maxim Integrated Products, Inc.

Features

- ◆ **Compact Layout**
 - Small, 1.25mm x 1.25mm WLP Package
 - 3MHz PWM Switching Frequency
 - Small External Components
- ◆ **Safe and Efficient Step-Up Mode**
 - Up to 1A Output Current
 - 2.5V to 5.5V Input Voltage Range
 - 3.3V to 5V Output Voltage Range
 - Over 90% Efficiency with Internal Synchronous Rectifier
 - Low 45 μ A No-Load Quiescent Current
 - Soft-Start Controls Inrush Current
 - True Shutdown™
 - Low 1 μ A Shutdown Current
- ◆ **Track Mode**
 - 1A Current Limited
 - 130m Ω On-Resistance
 - Low 30 μ A No Load Quiescent Current
- ◆ **Automatic Track Mode**
 - 130m Ω On-Resistance
 - Low 60 μ A No-Load Quiescent Current
 - Boost Circuitry Enabled for Fast Transition into Boost

Ordering Information

PART	V _{OUT} (V)	TEMP RANGE	PIN-PACKAGE
MAX8969EWL33+	3.3	-40°C to +85°C	9 WLP
MAX8969EWL35+	3.5	-40°C to +85°C	9 WLP
MAX8969EWL37+	3.7	-40°C to +85°C	9 WLP
MAX8969EWL42+	4.25	-40°C to +85°C	9 WLP
MAX8969EWL50+	5.0	-40°C to +85°C	9 WLP

Note: The output voltage range is from 3.3V to 5V. Contact the factory for output options and availability.

+Denotes a lead(Pb)-free/RoHS-compliant package.



Step-Up Converter for Handheld Applications

ABSOLUTE MAXIMUM RATINGS

IN, OUT_ to GND_.....	-0.3V to +6.0V	Operating Temperature Range.....	-40°C to +85°C
EN, TREN to GND_.....	-0.3V to lower of (V _{IN} + 0.3V) or 6V	Junction Temperature.....	+150°C
Total LX_ Current.....	3.2A _{RMS}	Storage Temperature Range.....	-65°C to +150°C
OUT_ Short Circuit to GND_.....	Continuous	Soldering Temperature (reflow) (Note 1).....	+260°C
Continuous Power Dissipation (T _A = +70°C)			
WLP (derate 12mW/°C above +70°C).....	960mW		

Note 1: This device is constructed using a unique set of packaging techniques that impose a limit on the thermal profile that the device can be exposed to during board level solder attach and rework. This limit permits only the use of the solder profiles recommended in the industry-standard specification JEDEC 020A, paragraph 7.6, Table 3 for IR/VPR and Convection reflow. Preheating is required. Hand or wave soldering is not allowed.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

PACKAGE THERMAL CHARACTERISTICS (Note 2)

WLP

Junction-to-Ambient Thermal Resistance (θ _{JA}).....	83°C/W
Junction-to-Case Thermal Resistance (θ _{JC}).....	50°C/W

Note 2: Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to www.maxim-ic.com/thermal-tutorial.

ELECTRICAL CHARACTERISTICS

(V_{IN} = 2.6V, T_A = -40°C to +85°C, unless otherwise noted. Typical values are T_A = +25°C.) (Note 3)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Operating Input Voltage Range		2.5		5.5	V
Minimum Startup Voltage			2.3		V
Undervoltage Lockout Threshold (UVLO)	V _{IN} falling, 75mV hysteresis	2.1	2.2	2.3	V
Shutdown Supply Current	V _{EN} = V _{TREN} = V _{OUT} = 0V, V _{IN} = 4.8V	T _A = +25°C	0.8	5	μA
		T _A = +85°C	1		
Thermal Shutdown	T _A rising, 20°C hysteresis		+165		°C
BOOST MODE					
Peak Output Current	V _{IN} > 2.5V (Note 4)	1			A
Continuous Output Current	V _{IN} > 2.5V, pulse load	V _{OUT} = 3.3V	0.9		A
		V _{OUT} = 3.5V	0.8		
		V _{OUT} = 3.7V	0.7		
		V _{OUT} = 4.25V	0.7		
		V _{OUT} = 4.7V	0.7		
		V _{OUT} = 5.0V	0.7		
Switching Frequency	(Note 4)		3		MHz
Output Voltage Accuracy	No load, V _{OUT_TARGET} = 3.3V	3.175	3.30	3.40	V
	No load, V _{OUT_TARGET} = 3.5V	3.40	3.50	3.60	
	No load, V _{OUT_TARGET} = 3.7V	3.64	3.75	3.85	
	No load, V _{OUT_TARGET} = 4.25V	4.10	4.25	4.35	
	No load, V _{OUT_TARGET} = 5V	4.85	5.00	5.10	

Step-Up Converter for Handheld Applications

MAX8969

ELECTRICAL CHARACTERISTICS (continued)

($V_{IN} = 2.6V$, $T_A = -40^{\circ}C$ to $+85^{\circ}C$, unless otherwise noted. Typical values are $T_A = +25^{\circ}C$.) (Note 3)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Steady-State Output Voltage (Notes 5, 6)	$2.5V < V_{IN} < V_{ATMRT}$, conditions emulating $0 < I_{OUT} < 1A$, $C_{OUT} = 22\mu F$, $L = 1\mu H$, $V_{OUT_TARGET} = 3.3V$	3.00		3.45	V
	$2.5V < V_{IN} < V_{ATMRT}$, conditions emulating $0 < I_{OUT} < 1A$, $C_{OUT} = 22\mu F$, $L = 1\mu H$, $V_{OUT_TARGET} = 3.5V$	3.15		3.65	
	$2.5V < V_{IN} < V_{ATMRT}$, conditions emulating $0 < I_{OUT} < 1A$, $C_{OUT} = 22\mu F$, $L = 1\mu H$, $V_{OUT_TARGET} = 3.7V$	3.35		3.85	
	$2.5V < V_{IN} < V_{ATMRT}$, conditions emulating $0 < I_{OUT} < 600mA$, $C_{OUT} = 22\mu F$, $L = 1\mu H$, $V_{OUT_TARGET} = 4.25V$	3.95		4.35	
	$2.5V < V_{IN} < V_{ATMRT}$, conditions emulating $0 < I_{OUT} < 500mA$, $C_{OUT} = 22\mu F$, $L = 1\mu H$, $V_{OUT_TARGET} = 5V$	4.50		5.10	
LX_ Leakage Current	$V_{LX} = 0V, 4.8V$	$T_A = +25^{\circ}C$	0.1	5	μA
		$T_A = +85^{\circ}C$	0.2		
Skip-Mode Supply Current	$EN = high, I_{OUT} = 0A, 1\mu H$ inductor (TREN is low, not switching)		45		μA
pMOS Turn-Off Current (Zero-Cross Current)			10		mA
LX_ nMOS Current Limit			2.6	3.2	A
Maximum Duty Cycle			83		%
Minimum Duty Cycle		0			%
pMOS On-Resistance	$V_{OUT} = 3.3V$		120		$m\Omega$
	$V_{OUT} = 3.5V$		115		
	$V_{OUT} = 3.7V$		110		
	$V_{OUT} = 4.25V$		100		
	$V_{OUT} = 5V$		91		
nMOS On-Resistance	$V_{OUT} = 3.3V$		65		$m\Omega$
	$V_{OUT} = 3.5V$		63		
	$V_{OUT} = 3.7V$		60		
	$V_{OUT} = 4.25V$		55		
	$V_{OUT} = 5V$		51		
Minimum Output Capacitance for Stable Operation (Actual)			8		μF
Maximum Output Capacitance (Actual)	$0 < I_{OUT} < 0.3A$ during startup	$V_{OUT} = 3.3V$	70		μF
		$V_{OUT} = 3.5V$	55		
		$V_{OUT} = 3.7V$	45		
		$V_{OUT} = 4.25V$	30		
		$V_{OUT} = 5V$	20		

Step-Up Converter for Handheld Applications

ELECTRICAL CHARACTERISTICS (continued)

($V_{IN} = 2.6V$, $T_A = -40^{\circ}C$ to $+85^{\circ}C$, unless otherwise noted. Typical values are $T_A = +25^{\circ}C$.) (Note 3)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS	
Output Voltage Ripple	$I_{OUT} = 150mA$, circuit of Figure 1		20		mVp-p	
Soft-Start Interval	$I_{OUT} = 10mA$, see the <i>Output Capacitor Selection</i> section				μs	
TRACK MODE						
pMOSFET On-Resistance	$I_{OUT} = 500mA$, $V_{IN} = 2.7V$		130		m Ω	
	$I_{OUT} = 500mA$, $V_{IN} = 3.2V$		110			
Track Current Limit	$V_{OUT} = 3.6V$	1	2		A	
Track Mode Quiescent Current	EN = low, TREN = high		30		μA	
AUTOMATIC TRACK MODE (ATM)						
ATM Supply Current	$V_{IN} = 5.4V$		65		μA	
ATM V_{IN} Rising Threshold (VATMRT)	$V_{OUT_TARGET} = 3.3V$		3.15		V	
	$V_{OUT_TARGET} = 3.5V$		3.35			
	$V_{OUT_TARGET} = 3.7V$		3.55			
	$V_{OUT_TARGET} = 4.25V$		4.04			
	$V_{OUT_TARGET} = 5V$		4.74			
ATM V_{IN} Falling Threshold (VATMFT)	$V_{OUT_TARGET} = 3.3V$		3.10		V	
	$V_{OUT_TARGET} = 3.5V$		3.29			
	$V_{OUT_TARGET} = 3.7V$		3.5			
	$V_{OUT_TARGET} = 4.25V$		3.99			
	$V_{OUT_TARGET} = 5V$		4.69			
Boost to ATM Transition Time	(Note 7)		1		μs	
ATM to Boost Transition Time			1		μs	
LOGIC CONTROL						
EN, TREN Logic Input High Voltage	$2.3V < V_{IN} < 5.5V$	1.05			V	
EN, TREN Logic Input Low Voltage	$2.3V < V_{IN} < 5.5V$			0.4	V	
EN, TREN Leakage Current	$V_{EN} = V_{TREN} = 0V$	$T_A = +25^{\circ}C$	-1	0.01	+1	μA
		$T_A = +85^{\circ}C$		0.1		

Note 3: Specifications are 100% production tested at $T_A = +25^{\circ}C$. Limits over the operating temperature range are guaranteed by design and characterization.

Note 4: Continuous operation with 1A at elevated ambient temperature and low voltage is not guaranteed. Under worst-case conditions, die thermal protection cannot be activated after 100ms of 1A load application. See the continuous output current parameter for a conservative estimate of current that can be maintained at $T_A = +85^{\circ}C$.

Note 5: Switching frequency decreases if input voltage is $> 83\%$ of the output voltage selected. This allows duty factor to drop to values necessary to boost output voltage less than 25% without the use of pulse widths less than 60ns.

Note 6: Contact factory for other options.

Note 7: The output voltage regulation is a direct function of the peak current in the nMOS power switch. The inductor current (I_{LX}) described in the conditions of the steady-state output voltage specification corresponds to the peak inductor current.

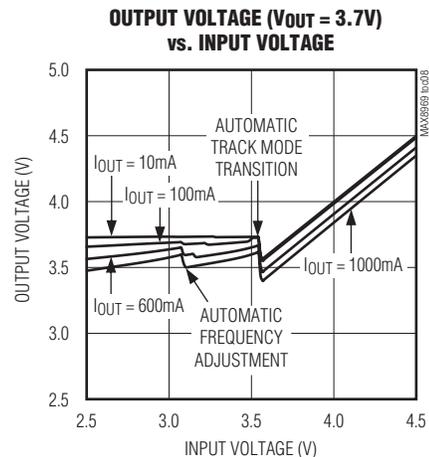
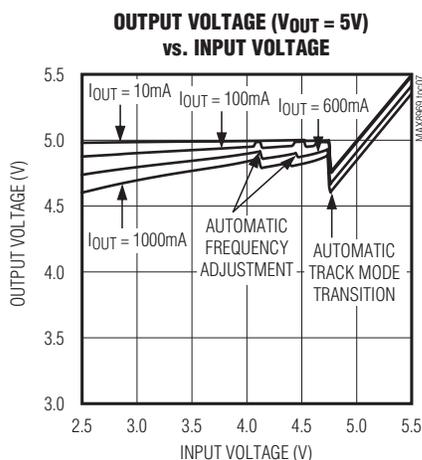
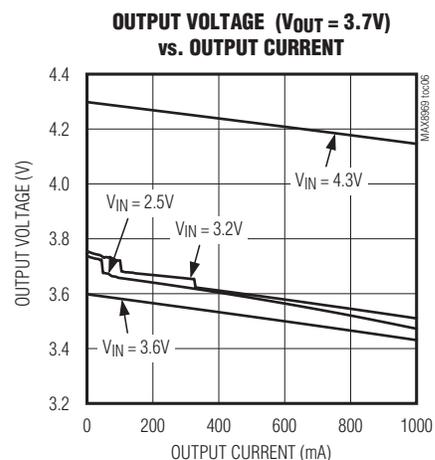
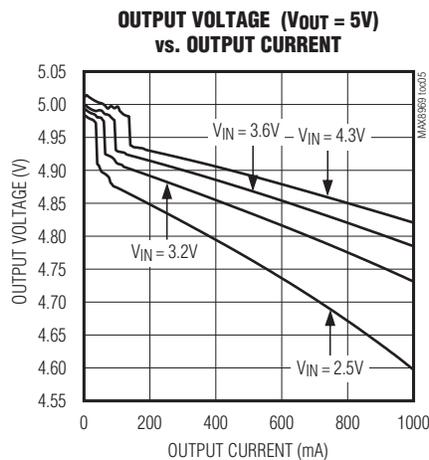
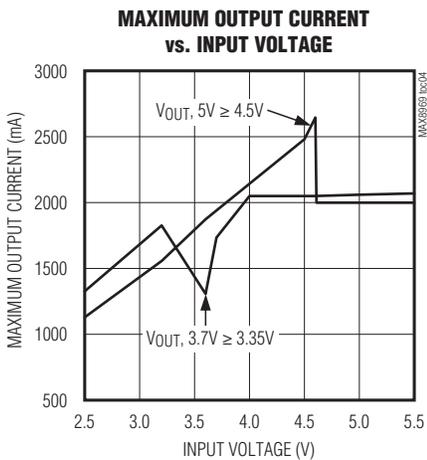
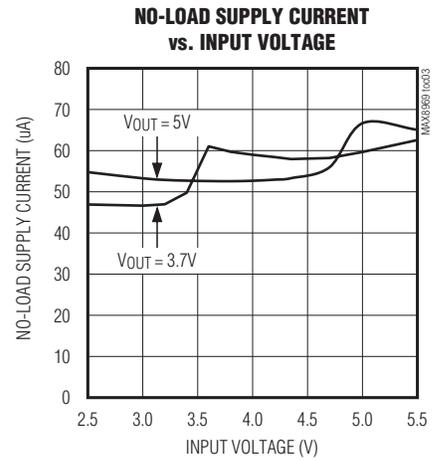
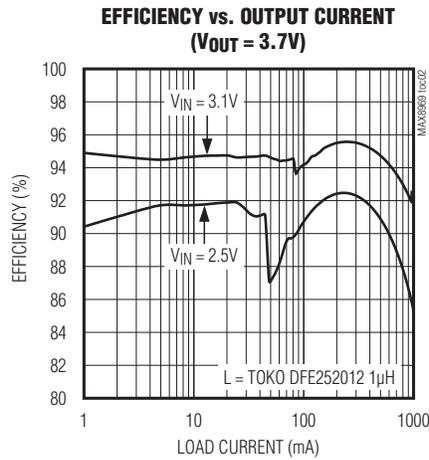
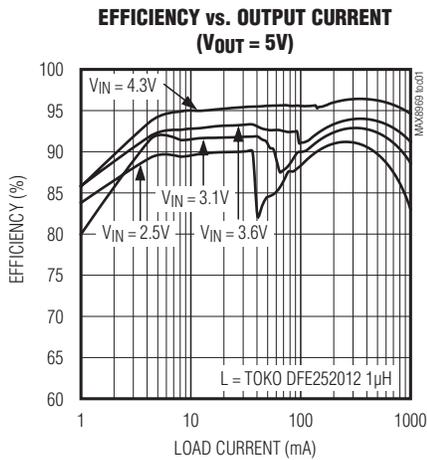
Note 8: Once ATM threshold is reached boost switching stops in 1 μs (typ), but the transition to ATM does not occur until V_{OUT} has fallen equal to V_{IN} .

Step-Up Converter for Handheld Applications

Typical Operating Characteristics

($V_{IN} = 3.6V$, $C_{OUT} = 22\mu F$, X5R, 6.3V local and $10\mu F$, X5R, 6.3V, $1\mu H$ inductor, circuit of Figure 1, $T_A = +25^\circ C$, unless otherwise noted.)

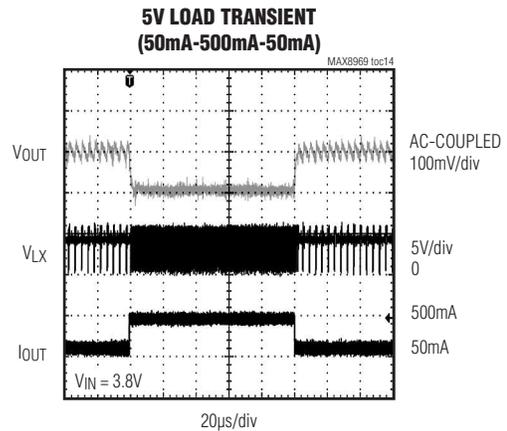
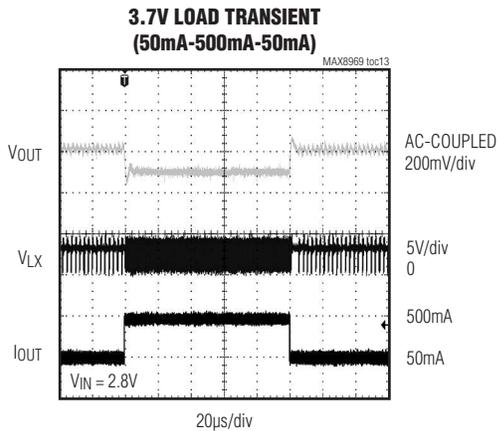
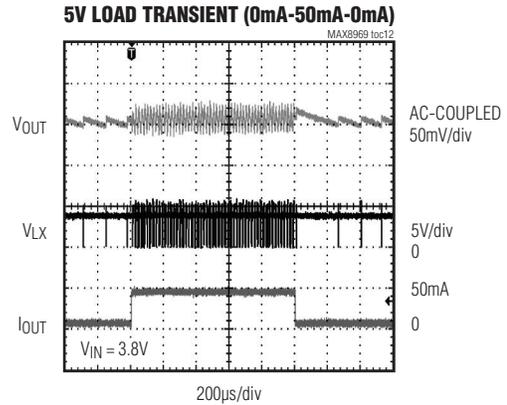
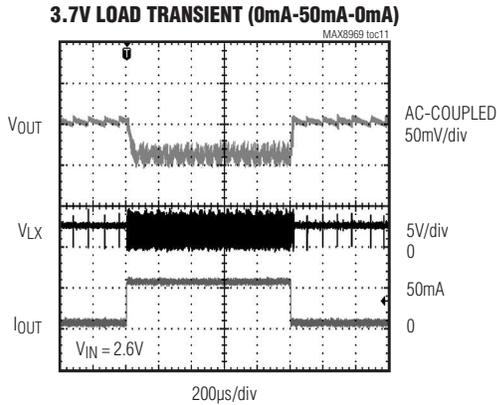
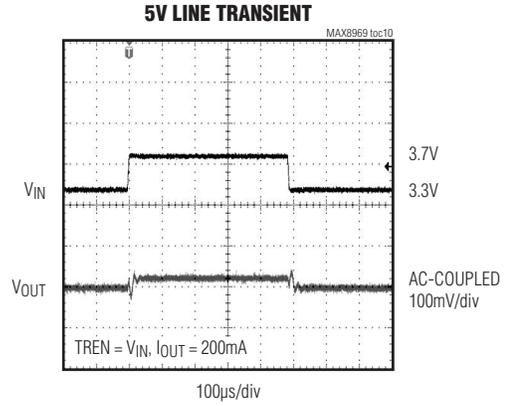
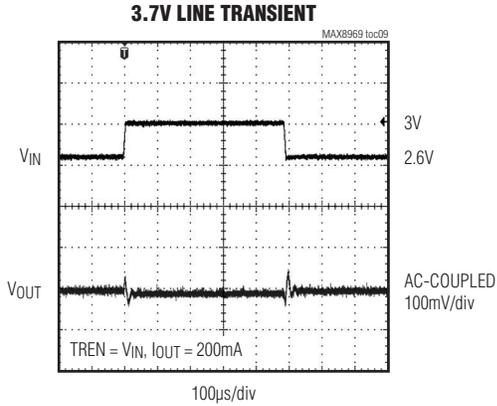
MAX8969



Step-Up Converter for Handheld Applications

Typical Operating Characteristics (continued)

($V_{IN} = 3.6V$, $C_{OUT} = 22\mu F$, X5R, 6.3V local and $10\mu F$, X5R, 6.3V, $1\mu H$ inductor, circuit of Figure 1, $T_A = +25^\circ C$, unless otherwise noted.)

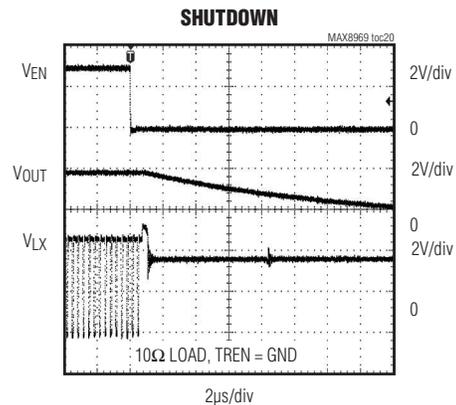
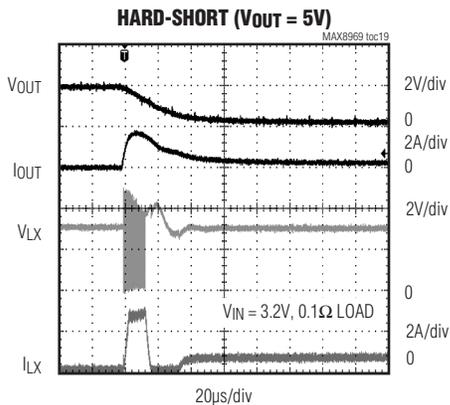
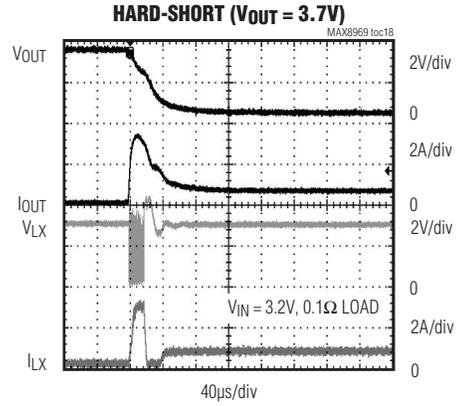
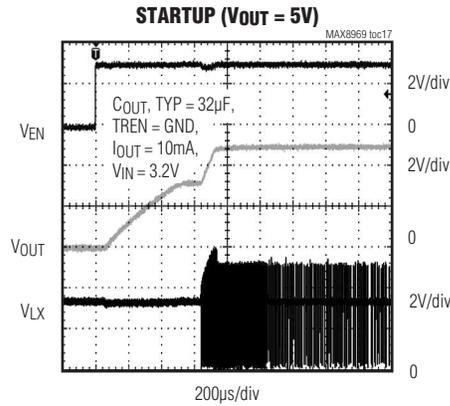
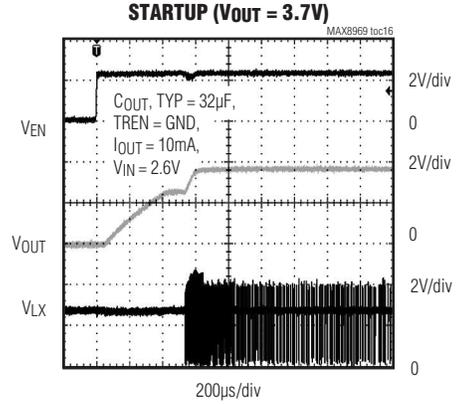
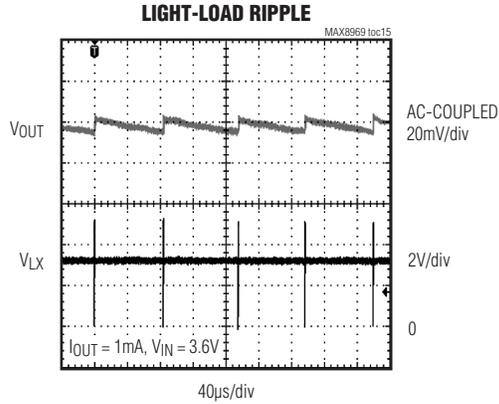


Step-Up Converter for Handheld Applications

Typical Operating Characteristics

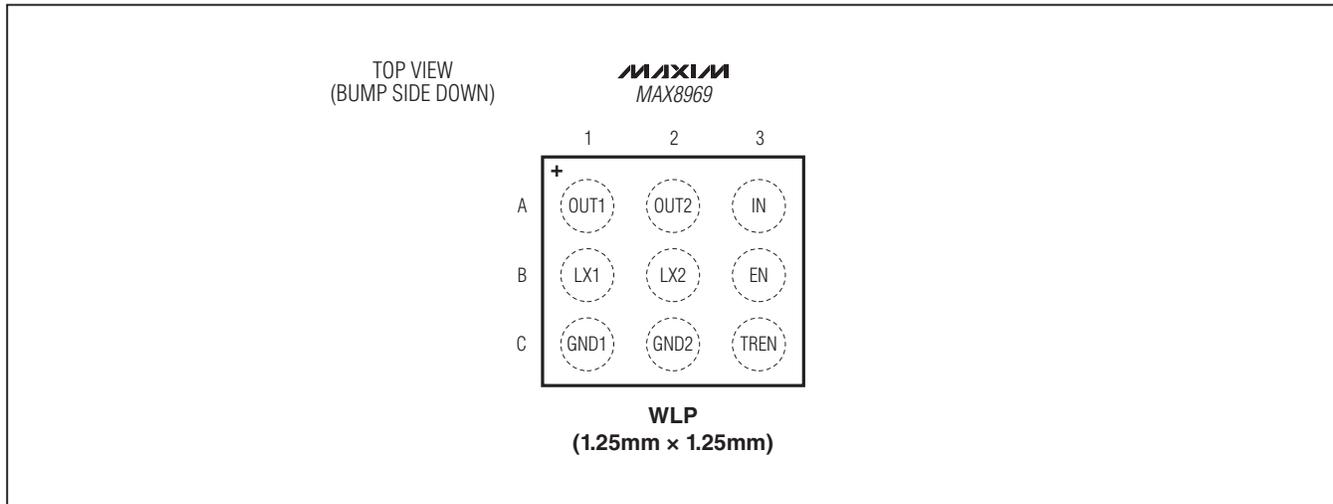
($V_{IN} = 3.6V$, $C_{OUT} = 22\mu F$, X5R, 6.3V local and $10\mu F$, X5R, 6.3V, $1\mu H$ inductor, circuit of Figure 1, $T_A = +25^\circ C$, unless otherwise noted.)

MAX8969



Step-Up Converter for Handheld Applications

Pin Configuration



Pin Description

PIN	NAME	FUNCTION
A1	OUT1	Power Output. Bypass OUT ₊ to ground with a 22μF rated ceramic capacitor. For optimal performance place the ceramic capacitor as close as possible to OUT ₊ . OUT1 and OUT2 should be shorted together directly under the IC. In True Shutdown, the output voltage can fall to 0V, but OUT ₊ has a diode with its cathode connected to IN. See Figure 3.
A2	OUT2	
A3	IN	Input Supply Voltage. Bypass IN to GND ₊ with a 4.7μF ceramic capacitor. A larger capacitance may be required to reduce noise.
B1	LX1	Converter Switching Node. Connect a 1μH inductor from LX ₊ to IN. LX ₊ is high impedance in shutdown. LX1 and LX2 should be shorted together directly under the IC.
B2	LX2	
B3	EN	Enable Input. Drive EN logic-high to enable boost mode, regardless of the logic level of TREN. Connect EN to ground or drive logic-low to allow TREN to select either True Shutdown or track mode. See Table 1.
C1	GND1	Ground. Connect GND ₊ to a large ground plane. GND1 and GND2 should be shorted together directly under the IC.
C2	GND2	
C3	TREN	Track Enable Input. Drive TREN logic-high to enable track mode. Connect TREN to ground or drive logic-low to place the IC in True Shutdown. See Table 1.

Step-Up Converter for Handheld Applications

MAX8969

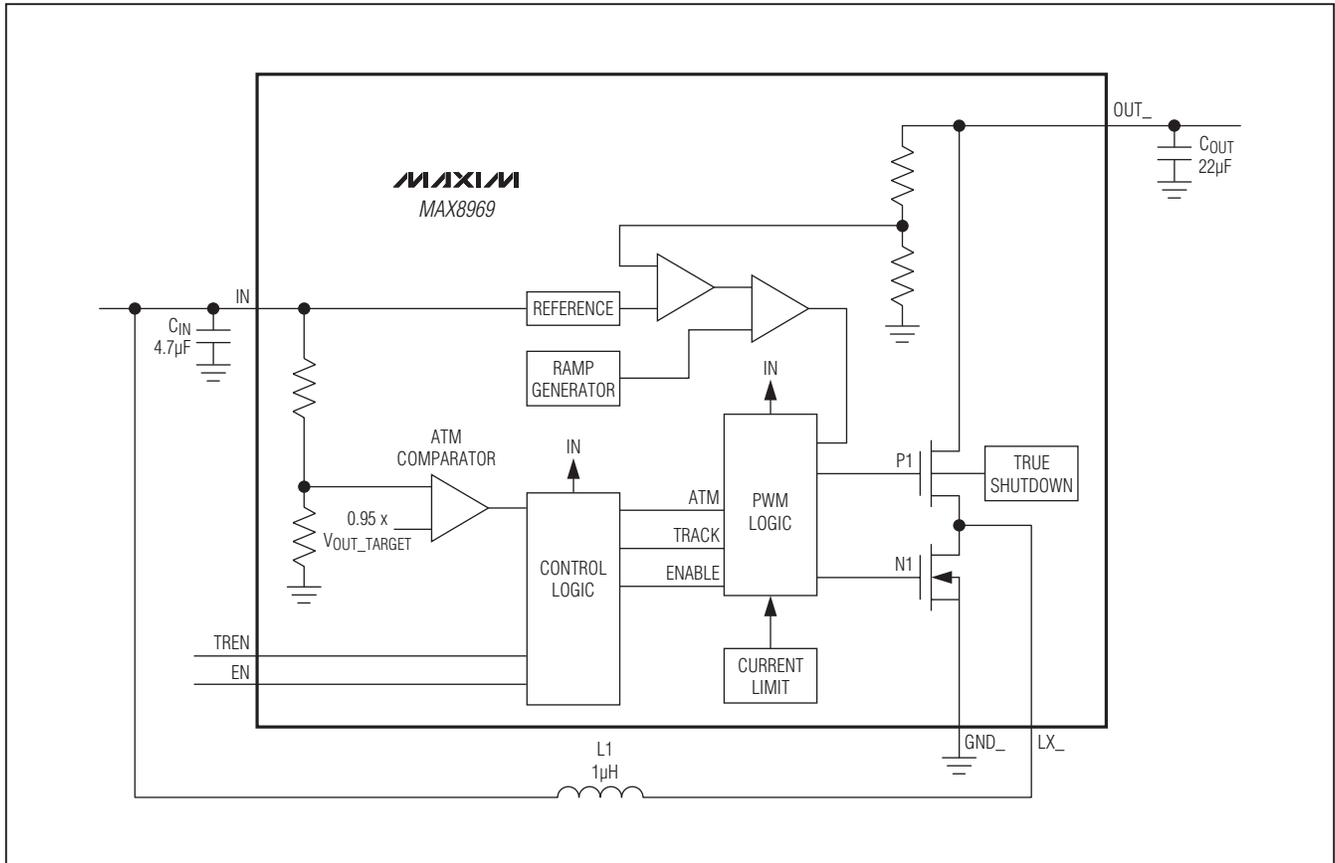


Figure 1. Functional Diagram

Detailed Description

The MAX8969 is a step-up DC-DC switching converter that utilizes a fixed-frequency PWM architecture with True Shutdown. With an advanced voltage-positioning control scheme and high 3MHz switching frequency, the IC is inexpensive to implement and compact, using only a few small easily obtained external components. Under light-load conditions, the IC switches only when needed, consuming only 45µA (typ) of quiescent current. The IC is highly efficient with an internal switch and synchronous rectifier. Shutdown typically reduces the quiescent current to 1µA (typ). Low quiescent current and high efficiency make this device ideal for powering portable equipment.

Internal soft-start limits inrush current to less than 720mA (typ), while output voltage is less than input voltage. Once output voltage approaches input voltage, output voltage is boosted to its final value at a rate of approximately 25mV/µs.

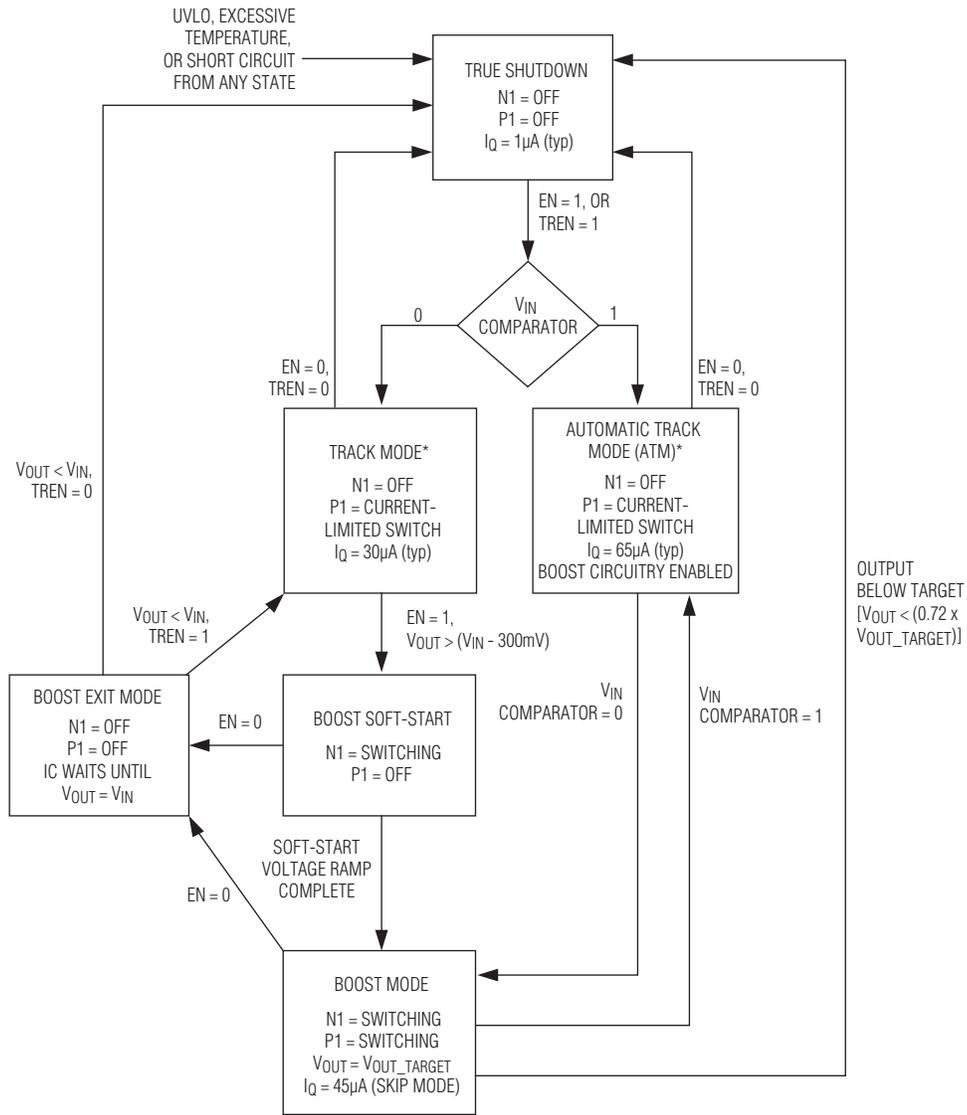
During this period, as well as being limited by the voltage, ramp rate current is limited by the normal 2.6A boost mode current limit.

In boost mode, the step-up converter boosts to V_{OUT_TARGET} from battery input voltages ranging from 2.5V to V_{OUT_TARGET} . When the input voltage ranges from $0.95 \times V_{OUT_TARGET}$ to 5.5V, the IC enters ATM and the output voltage approximately follows the input voltage. During boost mode, the input current limit is set to 2.6A to guarantee delivery of the rated out current (e.g., 1A output current when boosting from a 2.5V input supply to a 3.7V output).

Control Scheme

The step-up converter uses a load/line control scheme. The load/line control scheme allows the output voltage to sag under load, but prevents overshoot when the load is suddenly removed. The load/line control scheme reduces the total range of voltages reached during transients at the expense of DC output impedance.

Step-Up Converter for Handheld Applications



*EN TAKES PRIORITY OVER TREN. SEE TABLE 1.

Figure 2. State Diagram

Step-Up Converter for Handheld Applications

MAX8969

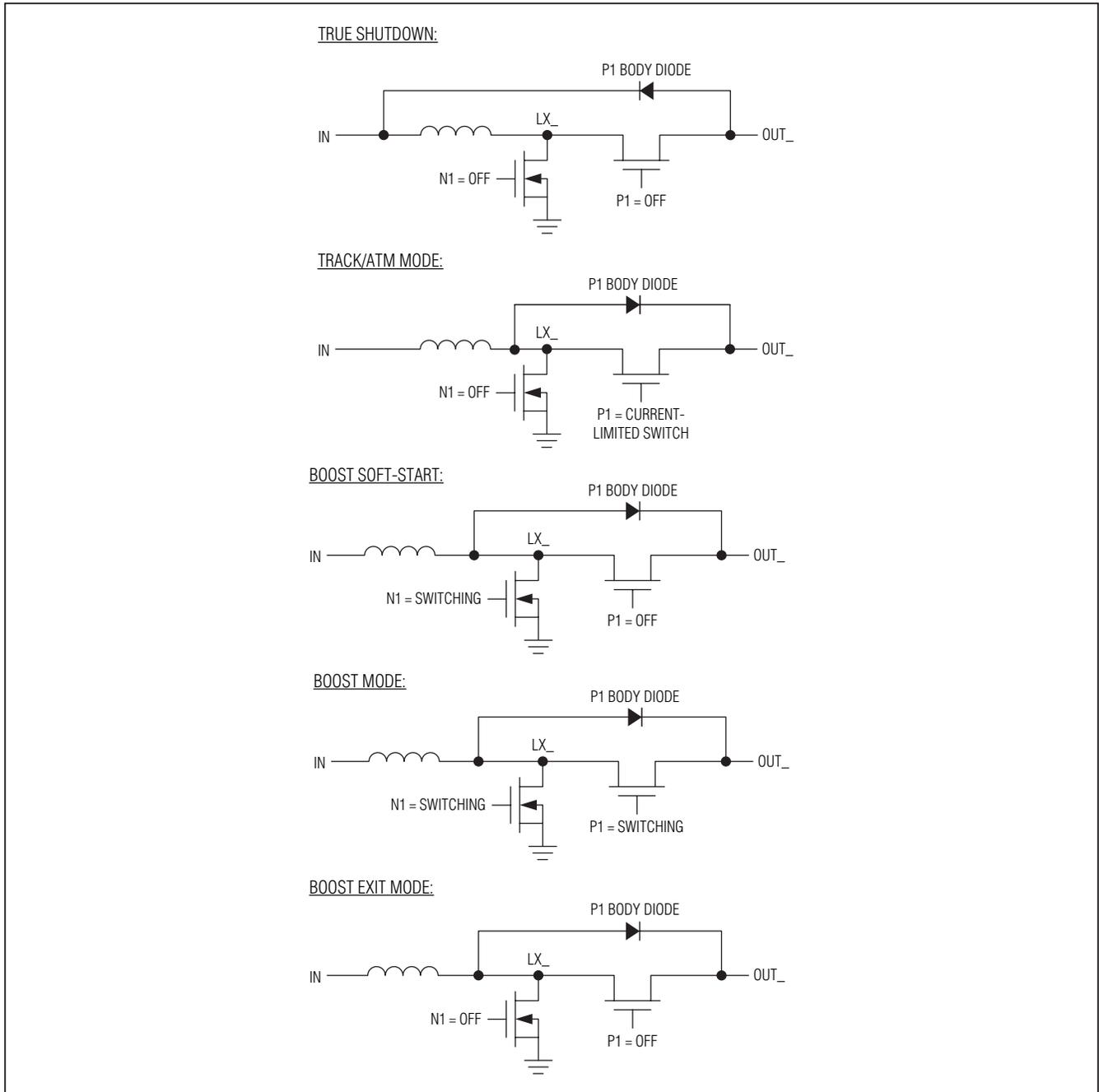


Figure 3. Modes of Operation

Step-Up Converter for Handheld Applications

The IC is designed to operate with the input voltage range straddling its output voltage set point. Two techniques are used to accomplish this. The first technique is to activate ATM if the input voltage exceeds 95% of the output set point; see the *Automatic Track Mode (ATM)* section. The second technique is automatic frequency adjustment.

Automatic Track Mode (ATM)

ATM is entered when an internal comparator signals that the input voltage has exceeded the ATM threshold. The ATM threshold is 95% of the output voltage target. At this point, the IC enters ATM, with the pMOS switch turned on, regardless of the status of TREN. Note that EN must be high to enable ATM mode. This behavior is summarized in Table 1.

Automatic Frequency Adjustment

Automatic frequency adjustment is used to maintain stability if the input voltage is above 80% and below 95% of the output set point. Frequency adjustment is required because the n-channel has a minimum on-time of approximately 60ns. At 3MHz, this would lead to the p-channel having a maximum duty factor of 82%. With an input voltage more than 82% of the output set point, the p-channel's duty factor must be increased by reducing operating frequency either through cycle skipping or adjusting the clock's frequency. The IC adjusts its clock frequency rather than simply skipping cycles. This adjustment is done in two steps. The first step occurs if the input voltage exceeds approximately 83% of the output voltage and reduces clock speed to approximately 1.6MHz. The second step occurs if the input voltage is greater than output voltage less 460mV. If this condition is met, clock frequency is reduced to approximately 1MHz. Frequency adjustment allows the converter to operate at a known frequency under all conditions.

Fault Protection

In track, ATM, and boost modes, the IC has protection against overload and overheating.

- In track and ATM, current is limited to prevent excessive inrush current during soft-start and to protect against overload conditions. If the die temperature exceeds +165°C in track/ATM, the switch turns off until the die temperature has cooled to +145°C.
- In boost mode, during each 3MHz switching cycle, if the inductor current exceeds 2.6A, the n-channel MOSFET is shut off and the p-channel MOSFET is switched on. The end result is that LX_ current is regulated to 2.6A or less. A 2.6A inductor current is a large enough current to guarantee a 1A output load current under all intended operating conditions. The IC can operate indefinitely while regulating the inductor current to 2.6A or less.

However, if a short circuit or extremely heavy load is applied to the output, the output voltage decreases since the inductor current is limited to 2.6A.

If the output voltage decreases to less than 72% of the regulation voltage target (i.e., 2.8V with VOUT_TARGET of 3.7V), a short circuit is assumed, and the IC returns to the shutdown state. The IC then attempts to start up if the output short is removed. Even if the output short persists indefinitely, the IC thermal protection ensures that the die is not damaged.

True Shutdown

During operation in boost mode, the p-channel MOSFET prevents current from flowing from OUT_ to LX_. In all other modes of operation, it is desirable to block current flowing from LX_ to OUT_. True Shutdown prevents current from flowing from LX_ to OUT_ while the IC is shut down by reversing the internal body diode of the p-channel MOSFET. This feature is also active during track/ATM to allow current limit to function as anticipated.

Upon leaving boost mode, the p-channel MOSFET continues to prevent current from flowing from OUT_ to LX_ until OUT_ and IN are approximately the same voltage. After this condition has been met, track/ATM and shutdown operate normally.

Table 1. Modes of Operation

V _{IN} COMPARATOR	EN	TREN	MODE OF OPERATION
X	0	0	True Shutdown
X	0	1	Track
0	1	X	Boost
1	1	X	ATM

X = Don't care.

Step-Up Converter for Handheld Applications

Thermal Considerations

In most applications, the IC does not dissipate much heat due to its high efficiency. But in applications where the IC runs at high ambient temperature with heavy loads, the heat dissipated may cause the temperature to exceed the maximum junction temperature of the part. If the junction temperature reaches approximately +165°C, the thermal overload protection is activated.

The maximum power dissipation depends on the thermal resistance of the IC package and circuit board. The power dissipated (P_D) in the device is:

$$P_D = P_{OUT} \times (1/\eta - 1)$$

where η is the efficiency of the converter and P_{OUT} is the output power of the step-up converter. The maximum allowed power dissipation is:

$$P_{MAX} = (T_{JMAX} - T_A)/\theta_{JA}$$

where $(T_{JMAX} - T_A)$ is the temperature difference between the IC's maximum rated junction temperature and the surrounding air, and θ_{JA} is the thermal resistance of the junction through the PCB, copper traces, and other materials to the surrounding air.

Applications Information

Step-Up Inductor Selection

Due to the small size of the recommended capacitor, the inductor's value is limited to approximately 1 μ H. Inductors of approximately 1 μ H guarantee stable operation of the converter with capacitance as small as 8 μ F (actual) present on the converter's output. If the inductor's value is reduced significantly below 1 μ H, ripple can become excessive.

Output Capacitor Selection

An output capacitor (C_{OUT}) is required to keep the output-voltage ripple small and to ensure regulation loop stability. The output capacitor must have low impedance at the switching frequency. Ceramic capacitors are highly recommended due to their small size and low ESR. Ceramic capacitors with X5R or X7R temperature characteristics generally perform well. One 22 μ F (with a minimum actual capacitance of 6 μ F under operating conditions) is recommended. This capacitor along with an additional 10 μ F of bypass capacitance, associated with the load, guarantee proper performance of the IC. The minimum combined capacitance is required to be 8 μ F or larger. These capacitors can be found with case size 0603 or larger.

Input Capacitor Selection

The input capacitor (C_{IN}) reduces the current peaks drawn from the battery or input power source. The impedance of C_{IN} at the switching frequency should be kept very low. Ceramic capacitors with X5R or X7R temperature characteristics are highly recommended due to their small size, low ESR, and small temperature coefficients. Note that some ceramic dielectrics exhibit large capacitance and ESR variation with temperature and DC bias. Ceramic capacitors with Z5U or Y5V temperature characteristics should be avoided. A 4.7 μ F input capacitor is recommended for most applications. This assumes that the input power source has at least 22 μ F of additional capacitance near the IC. For optimum noise immunity and low input-voltage ripple, the input capacitor value can be increased.

Recommended PCB Layout and Routing

Poor layout can affect the IC performance, causing electromagnetic interference (EMI) and electromagnetic compatibility (EMC) performance, ground bounce, and voltage losses. Poor layout can also affect regulation and stability.

A good layout is implemented using the following rules:

- Place the inductor, input capacitor, and output capacitor close to the IC using short traces. These components carry high switching frequencies and large traces act like antennas. The output capacitor placement is the most important in the PCB layout and should be placed directly next to the IC. The inductor and input capacitor placement are secondary to the output capacitor's placement but should remain close to the IC.
- Route the output voltage path away from the inductor and LX_ switching node to minimize noise and magnetic interference.
- Maximize the size of the ground metal on the component side to help with thermal dissipation. Use a ground plane with several vias connecting to the component-side ground to further reduce noise interference on sensitive circuit nodes.

Refer to the MAX8969 Evaluation Kit for more details.

Chip Information

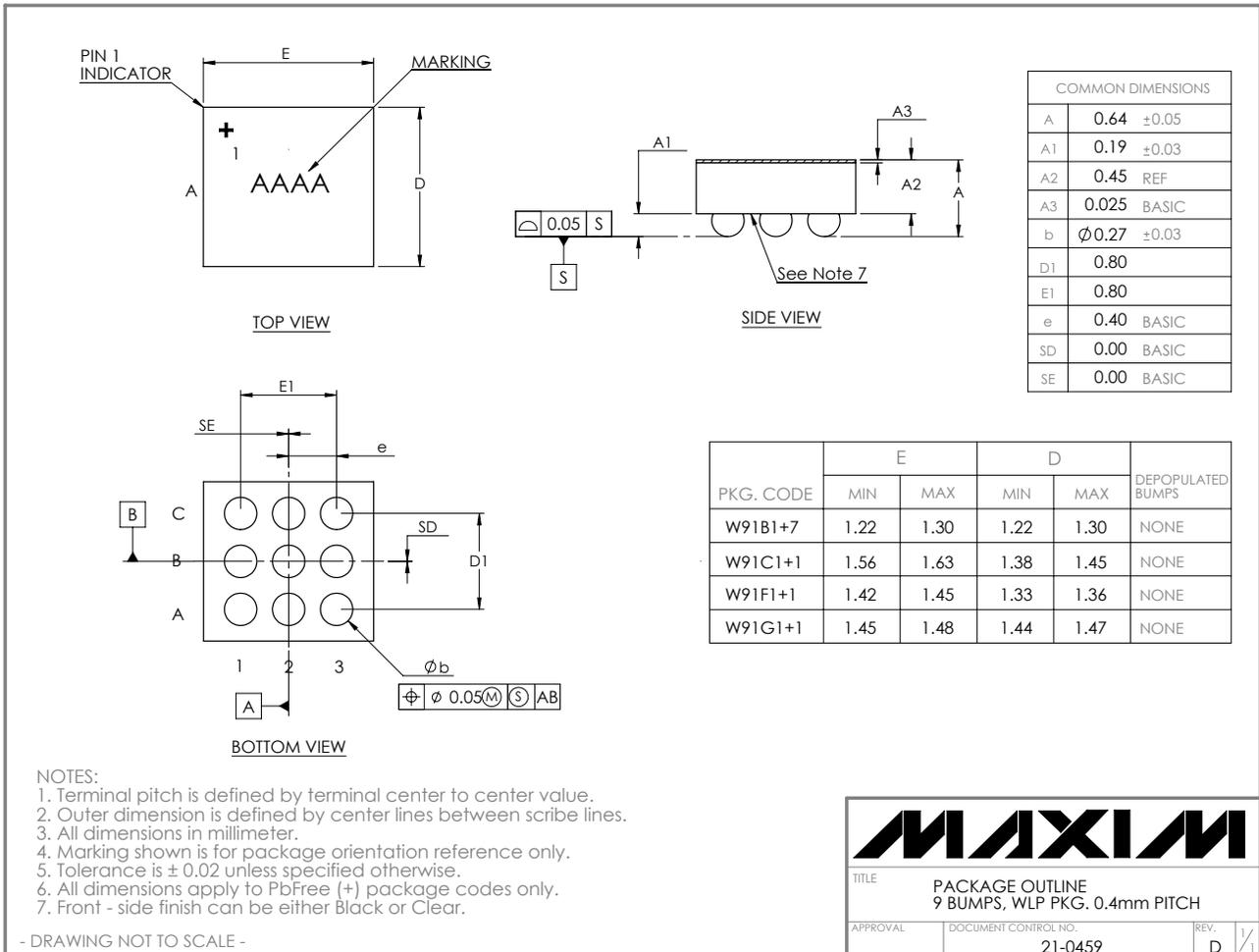
PROCESS: BiCMOS

Step-Up Converter for Handheld Applications

Package Information

For the latest package outline information and land patterns (footprints), go to www.maxim-ic.com/packages. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE TYPE	PACKAGE CODE	OUTLINE NO.	LAND PATTERN NO.
9 WLP	W91B1+7	21-0459	Refer to Application Note 1891



Step-Up Converter for Handheld Applications

Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	9/11	Initial release	—
1	5/12	Updated <i>Electrical Characteristics</i> table	2

MAX8969

Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

Maxim Integrated Products, 120 San Gabriel Drive, Sunnyvale, CA 94086 408-737-7600 _____ 15